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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild www.onsemi.com.

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Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter	Characteristics	
Installation Classifications per DIN VDE	< 150 V _{RMS}	I–IV
0110/1.89 Table 1, For Rated Mains Voltage	< 300 V _{RMS}	I–IV
Climatic Classification		55/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V_{PR}	Input-to-Output Test Voltage, Method A, V_{IORM} x 1.6 = V_{PR} , Type and Sample Test with t_{m}		

Note:

1. Safety limit values – maximum values allowed in the event of a failure.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Unit
TOTAL DEVI	CE		
T _{STG}	Storage Temperature	-40 to +125	°C
T_{OPR}	Operating Temperature	-40 to +100	°C

Typical Performance Characteristics

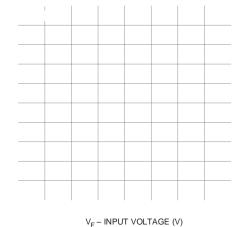
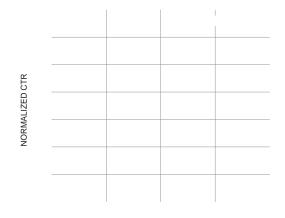
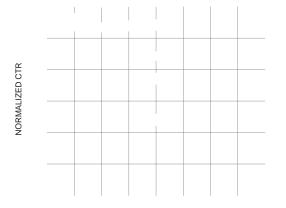


Figure 3. Input Voltage vs. Input Current

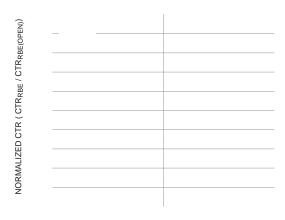


I_F – FORWARD CURRENT (mA)

Figure 4. Normalized CTR vs. Forward Current



T_A – AMBIENT TEMPERATURE (C)



R_{BE} – BASE RESISTANCE (k) Figure 6. CTR vs. RBE (Unsaturated)

Figure 5. Normalized CTR vs. Ambient Temperature

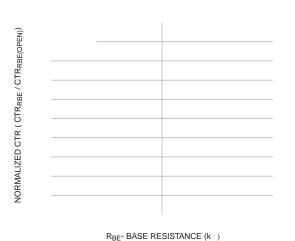


Figure 7. CTR vs. RBE (Saturated)

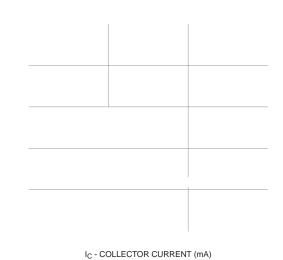


Figure 8. Collector-Emitter Saturation Voltage vs. Collector Current

VCE (SAT) - COLLECTOR-EMITTER SATURATION VOLTAGE (V)

Typical Performance Characteristics (Continued)

SWITCHING SPEED (s)

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Figure 9. Switching Speed vs. Load Resistor

R - LOAD RESISTOR (k)

R_{BE}- BASE RESISTANCE (k)

Figure 10. Normalized ton vs. RBE

 $\mathsf{NORMALIZED}\ t_{\mathsf{off}} - (t_{\mathsf{off}(\mathsf{RBE})}\ /\ t_{\mathsf{off}(\mathsf{open})})$

R

Figure 11. Normalized toff vs. RBE

Reflow Profile

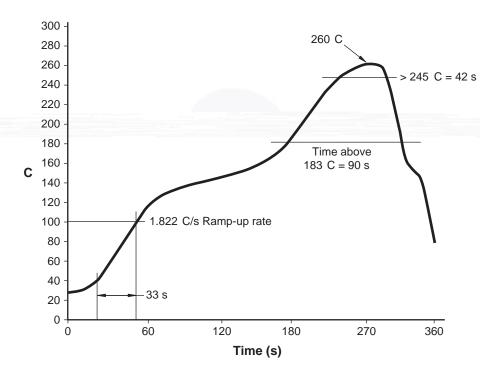


Figure 14. Reflow Profile



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